onsemi

Low-Power, Two-Port, High-Speed, USB2.0 (480 Mbps) UART Switch

FSUSB42

Description

The FSUSB42 is a bi-directional, low-power, two-port, high-speed, USB2.0 switch. Configured as a double-pole, double-throw switch (DPDT) switch, it is optimized for switching between any combination of high-speed (480 Mbps) or Full-Speed (12 Mbps) sources.

The FSUSB42 is compatible with the requirements of USB2.0 and features an extremely low on capacitance (CON) of 3.7 pF. The wide bandwidth of this device (720 MHz) exceeds the bandwidth needed to pass the third harmonic, resulting in signals with minimum edge and phase distortion. Superior channel-to-channel crosstalk also minimizes interference.

The FSUSB42 contains special circuitry on the switch I/O pins for applications where the V_{CC} supply is powered-of f ($V_{CC} = 0$ V), which allow s the device to withstand an over-voltage condition. This device is designed to minimize current consumption even when the control voltage applied to the SEL pin is low er than the supply voltage (V_{CC}). This feature is especially valuable to ultra-portable applications, such as cell phones, allowing for direct interface with the general-purpose I/Os of the baseband processor. Other applications include switching and connector sharing in portable cell phones, PDAs, digital cameras, printers, and notebook computers.

Features

- Low On Capacitance: 3.7 pF Typical
- Low On Resistance: 3.9 Ω Typical
- Low Pow er Consumption: 1 µA Maximum
 - 15 μA Maximum I_{CCT} over an Expanded Voltage Range (V_{IN} = 1.8 V, V_{CC} = 4.4 V)
- Wide –3 db Bandwidth: > 720 MHz
- Packaged in:
 - ◆ 10-Lead UMLP (1.4 x 1.8 mm)
 - ♦ 10-Lead MSOP
- 8 kV ESD Rating, >16 kV Power / GND ESD Rating
- Over–Voltage Tolerance (OVT) On All USB Ports Up to 5.25 V without External Components

Typical Applications

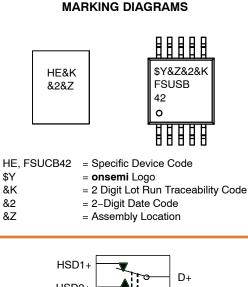
- Cell Phone, PDA, Digital Camera, and Notebook
- LCD Monitor, TV, and Set-Top Box





UQFN10 1.4 × 1.8, 0.4 P CASE 523BC

MSOP10 CASE 846AP



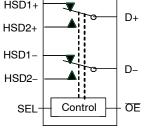


Figure 1. Analog Symbol

ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

Pin Assignments

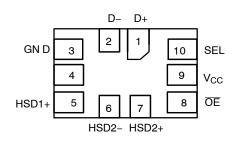


Figure 2. 10-Lead UMLP (Top-Through View)

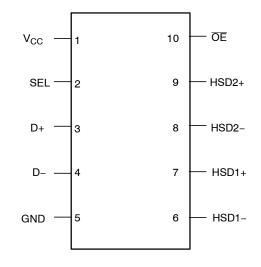


Figure 3. 10-Lead MSOP (Top-Through View)

PIN DESCRIPTION

UMLP Pin#	MSOP Pin#	Name	Description
1	3	D+	Common USB Data Bus
2	4	D-	Common USB Data Bus
3	5	GND	Ground
4	6	HSD1-	Multiplexed Source Input 1
5	7	HSD1+	Multiplexed Source Input 1
6	8	HSD2-	Multiplexed Source Input 2
7	9	HSD2+	Multiplexed Source Input 2
8	10	ŌĒ	Switch Enable
9	1	V _{CC}	Supply Voltage
10	2	SEL	Switch Select

TRUTH TABLE

SEL	ŌE	Function
X	HIGH	Disconnect
LOW	LOW	D+ = HSD1+, D- = HSD1-
HIGH	LOW	D+ = HSD2+, D- = HSD2-

1. LOW \leq V_{IL}. 2. HIGH \leq V_{IH}. 3. X = Don't Care.

ABSOLUTE MAXIMUM RATINGS

Symbol	Pa	Parameter			
V _{CC}	Supply Voltage		-0.5	5.6	V
V _{CNTRL}	DC Input Voltage (S, OE) (Note 4)		-0.5	V _{CC}	V
V _{SW}	DC Switch I/O Voltage (Note 4) (VCC	C = 0 V)	-0.50	5.25	V
I _{IK}	DC Input Diode Current		-50	-	mA
I _{OUT}	DC Output Current		-	100	mA
T _{STG}	Storage Temperature		-65	+150	°C
MSL	Moisture Sensitivity Level (JEDEC J-	-STD-020A)	-	1	Level
ESD	Human Body Model, JEDEC:	All Pins	7	-	kV
	JESD22-A114	I/O GND	8	-	
		Power to GND	16	-	
		D+/D-	9	-	
	IEC 61000-4-2 System on USB	Air Discharge	15	-	
	Connector Pins D+ & D-	Contact	8	-	1
	Charged Device Model, JEDEC: JES	D22-C101	2	-	1

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

4. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Мах	Unit
V _{CC}	Supply Voltage	2.4	4.4	V
V _{CNTRL}	Control Input Voltage (S, OE) (Note 5)	0	V _{CC}	V
V _{SW}	Switch I/O Voltage		4.5	V
T _A	Operating Temperature	-40	+85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

5. The control input must be held HIGH or LOW and it must not float.

DC ELECTRICAL CHARACTERISTICS

(All typical value are at $T_A = 25^{\circ}C$ unless otherwise specified.)

				T _A = -40°C to +85°C			
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
V _{IK}	Clamp Diode Voltage	I _{IN} = 18 mA	3.0	-	-	-1.2	V
V _{IH}	Input Voltage High		2.4 to 3.6	1.3	-	-	V
			4.3	1.7	-	-	
V _{IL}	Input Voltage Low		2.4 to 3.6	-	-	0.5	V
			4.3	-	-	0.7	
I _{IN}	Control Input Leakage	$V_{SW} = 0$ to V_{CC}	0 to 4.3	-1	-	1	μΑ
I _{OZ}	Off State Leakage	$0 \le Dn$, HSD1n, HSD2n $\le 3.6 \text{ V}$	4.3	-2	-	2	μΑ
I _{OFF}	Power-Off Leakage Current (All I/O Ports)	V_{SW} = 0 V to 4.3 V, V_{CC} = 0 V Figure 5	0	-2	-	2	μΑ
R _{ON}	HS Switch On Resistance	V _{SW} = 0.4 V, I _{ON} =8 mA	2.4	-	4.5	7.5	Ω
	(Note 6)	Figure 4	3.0	-	3.9	6.5	
ΔR_{ON}	HS Delta R _{ON} (Note 7)	V _{SW} = 0.4, I _{ON} = 8 mA	3.0	-	0.65	-	Ω
I _{CC}	Quiescent Supply Current	$V_{CNTRL} = 0$ or V_{CC} , $I_{OUT} = 0$	4.3	-	-	1	μΑ

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DC ELECTRICAL CHARACTERISTICS (continued)

(All typical value are at $T_A = 25^{\circ}C$ unless otherwise specified.)

				T _A = -40°C to +85°C			
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
I _{CCT}	Increase in I _{CC} Current per	V_{CNTRL} = 2.6, V_{CC} = 4.3 V	4.3	-	-	10	μA
	Control Voltage and V _{CC}	V_{CNTRL} = 1.8, V_{CC} = 4.3 V	4.3		-	15	μA

6. Measured by the voltage drop between HSDn and Dn pins at the indicated current through the switch. On resistance is determined by the lower of the voltage on the two (HSDn or Dn ports).

7. Guaranteed by characterization.

AC ELECTRICAL CHARACTERISTICS

(All typical value are for V_{CC} = 3.3 V at T_A = 25°C unless otherwise specified.)

				T _A = -	40°C to	+85°C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
t _{ON}	Turn-On Time	$R_{L} = 50 \Omega, C_{L} = 5 \text{ pF}, V_{SW} = 0.8 \text{ V},$	2.4	-	24	40	ns
	S, OE to Output	Figure 6, Figure 7	3.0 to 3.6	-	13	30	
t _{OFF}	Turn-Off Time	$R_{L} = 50 \Omega, C_{L} = 5 \text{ pF}, V_{SW} = 0.8 \text{ V},$	2.4	-	15	35	ns
	S, OE to Output	Figure 6, Figure 7	3.0 to 3.6	-	12	25	
t _{PD}	Propagation Delay (Note 8)	$C_L = 5 \text{ pF}, R_L = 50 \Omega,$ Figure 6, Figure 8	3.3	-	0.25	-	ns
t _{BBM}	Break-Before-Make	$R_{L} = 50 \Omega, C_{L} = 5 pF,$	2.4	2.0	-	10	ns
		V _{SW1} = V _{SW2} = 0.8 V, Figure 10	3.0 to 3.6	2.0	-	6.5	
O _{IRR}	Off Isolation	R_L = 50 Ω , f = 240 MHz, Figure 12	3.0 to 3.6	-	-30	-	dB
Xtalk	Non-Adjacent Channel Crosstalk	R_L = 50 Ω, f = 240 MHz, Figure 13	3.0 to 3.6	-	-45	-	dB
BW	-3 db Band Width	R _L = 50 Ω, C _L = 0 pF, Figure 11	3.0 to 3.6	-	720	-	MHz
		R_L = 50 Ω , C_L = 5 pF, Figure 11	1	-	550	-	MHz

8. Guaranteed by characterization.

USB HIGH-SPEED-RELATED AC ELECTRICAL CHARACTERISTICS

(All typical value are for V_{CC} = 3.3 V at T_A = 25°C unless otherwise specified.)

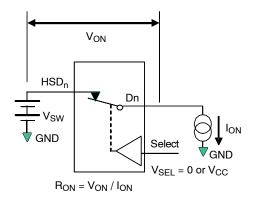
				T _A = −40°C to +85°C		C to +85°C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
t _{SK(P)}	Skew of Opposite Transition of the Same Output (Note 9)	C_L = 5 pF, R_L = 50 Ω , Figure 9	-	-	20	-	ps
tj	Total Jitter (Note 9)	$R_L = 50 Ω$, $C_L = 5 pF$, $t_R = t_F = 500 ps (10-90%) at$ 480 Mbps (PRBS = $2^{15} - 1$)	-	_	200	-	ps

9. Guaranteed by characterization.

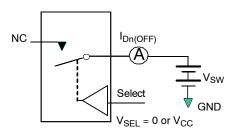
CAPACITANCE

			T _A = -40°C to +85°C			
Symbol	Parameter	Condition	Min	Тур	Max	Unit
C _{IN}	Control Pin Input Capacitance	V _{CC} = 0 V	-	1.5	-	pF
C _{ON}	D+/D- On Capacitance	V_{CC} = 3.3 V, \overline{OE} = 0 V, f = 240 MHz, Figure 15	-	3.7	-	pF
C _{OFF}	D1n, D2n Off Capacitance	V_{CC} and \overline{OE} = 3.3 V, Figure 14	-	2.0	-	pF

Test Diagrams

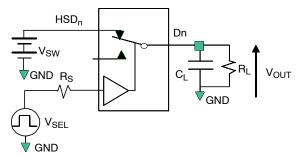






**Each switch port is tested separately

Figure 5. Off Leakage



 R_L , R_S , and C_L are functions of the application environment (see AC Tables for specific values) C_L includes test fixture and stray capacitance.



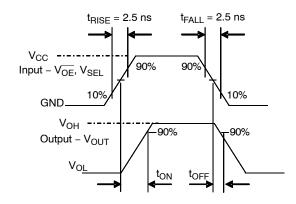


Figure 7. Turn-On / Turn-Off Waveforms

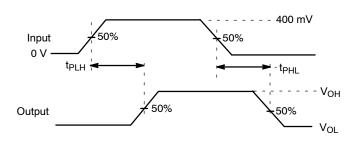


Figure 8. Propagation Delay (t_Rt_F – 500 ps)

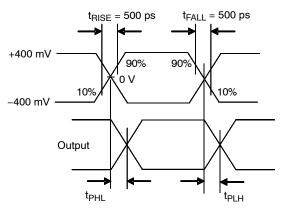


Figure 9. Intra-Pair Skew Test t_{SK(P)}

Test Diagrams (continued)

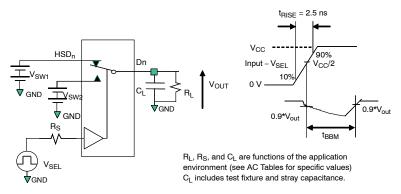


Figure 10. Break-Before-Make Interval Timing

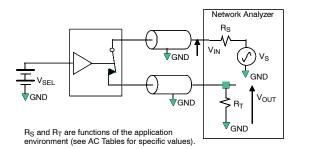


Figure 11. Bandwidth

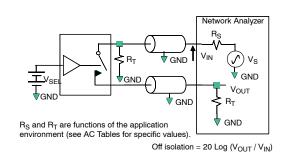


Figure 12. Channel Off Isolation

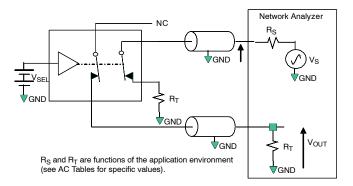


Figure 13. Non-Adjacent Channel-to-Channel Crosstalk

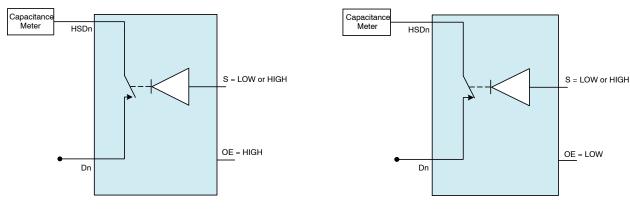




Figure 15. Channel On Capacitance

FSUSB42

ORDERING INFORMATION

Part Number	Device Code	Operating Temperature Range	Package	Shipping [†]
FSUSB42UMX	HE	-40 to 85°C	10-Lead, Quad, Ultrathin Molded Leadless Package (UQFN10), 1.4 × 1.8 mm	5000 / Tape and Reel
FSUSB42MUX	FSUSB42	−40 to 85°C	10-Lead, Molded Small-Outline Package (MSOP) JEDEC MO-187, 3.0 mm Wide	4000 / Tape and Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

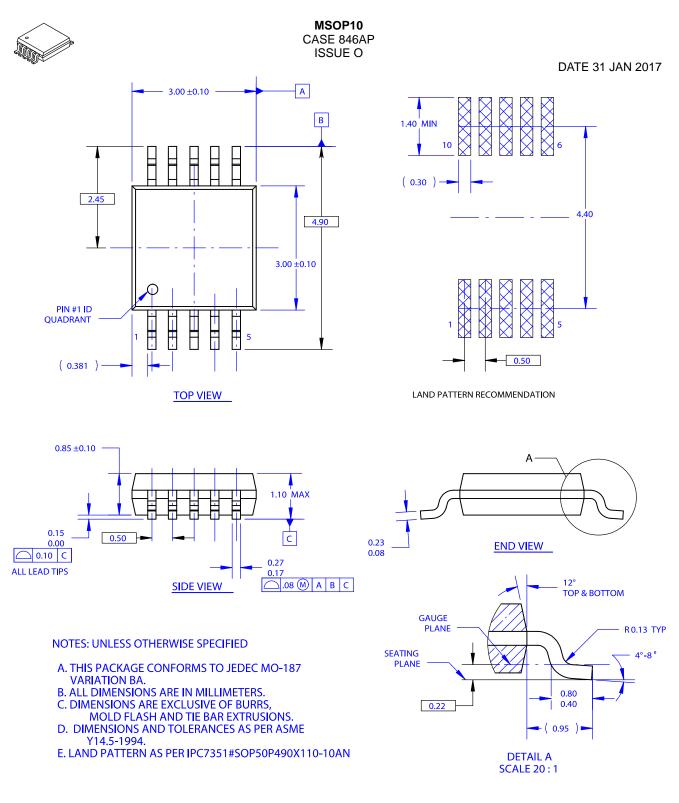


CASE	.4x1.8, 0.4F 523BC UE B)				
				DA	TE 13 MAY	2022
	NDTE	ES:				
2X D B PIN 1 REFERENCE C 0.05C TOP VIEW	1. 2. 3. 4.	ALL MILLIMET DIMENSIE TERMINAL BETWEEN	E Y14.5, DIMENSIO ERS IN & API _S AND N 0.15mm MINAL TII RITY AF PAD A	2018 INS AI PLIES TE IS AND 0.30	ERANCING RE IN D PLATED MEASURED Dmm FROM TO THE AS THE	
		DIM	MII	LIMETE	RS	
		2111	MIN.	NDM.	MAX.	
		A	0.45	0.50	0.55	
		A1	0.00	0.025	0.05	
SIDE VIEW		AЗ	0.	152 REF		
- - [e]		b	0.15	0.20	0.25	
9X L _ 3		D	1.35	1.40	1.45	
		E	1.75	1.80	1.85	
		е		0.40 BSC	2	
		L	0.35	0.40	0.45	
REFERENCE 1.25L BOTTOM VIEW 45* 0.4000 0.4000 0.4000 10X 0.225 DETAIL A DETAIL A DETIONAL CONSTRUCTIONS	RECOMN LAND PA	ATTERN IMENDED I strategy ownload t ting Tech	0.5 0 0, 10X 0, MOUNTING ormation and sol the onser nniques R	225	AL MINIMIA ND PATTER	NL

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